

Amendments to the Claims:

This listing of claims replaces all prior versions and listings of claims in the application:

Listing of Claims:

1. (Currently amended) A light emitting device comprising:
a thin film transistor over a substrate;
an interlayer insulating film over the thin film transistor; and
a pixel electrode over the interlayer insulating film; and
a storage capacitor **[[storage]]** over the interlayer insulating film,
wherein the storage capacitor **[[storage]]** has a connection wiring line, a capacitance wiring line, and an insulating film formed between the connection wiring line and the capacitance wiring line,
wherein the capacitance wiring line and the pixel electrode are formed on a same interlayer insulating film,
wherein the connection wiring line is connected to a source region or a drain region of the thin film transistor.
2. (Previously presented) A light emitting device as claimed in claim 1, wherein the insulating film is formed by anodization.
3. (Previously presented) A light emitting device as claimed in claims 1, wherein the capacitance wiring line and the pixel electrode are formed from the same conductive film.
4. (Original) An electric appliance comprising the light emitting device according to claim 1, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer,

a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

5. (Currently amended) A light emitting device comprising:
a thin film transistor over a substrate;
an interlayer insulating film over the thin film transistor; and
a pixel electrode over the interlayer insulating film; and
a storage capacitor **[[storage]]** over the interlayer insulating film,
wherein the storage capacitor **[[storage]]** has a connection wiring line, a capacitance wiring line, and an insulating film formed between the connection wiring line and the capacitance wiring line,
wherein the capacitance wiring line and the pixel electrode are formed on a same interlayer insulating film,
wherein the connection wiring line is connected to a source region or a drain region of the thin film transistor, and
wherein the connection wiring line overlaps an active layer of the thin film transistor.
6. (Previously presented) A light emitting device as claimed in claim 5, wherein the insulating film is formed by anodization.
7. (Previously presented) A light emitting device as claimed in claim 5, wherein the capacitance wiring line and a pixel electrode are formed from the same conductive film.
8. (Original) An electric appliance comprising the light emitting device according to claim 5, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

9. (Currently amended) A light emitting device comprising a thin film transistor, a storage capacitor, **[[storage,]]** and an organic light emitting diode,

wherein the storage capacitor **[[storage]]** has a connection wiring line, a capacitance wiring line, and an insulating film formed between the connection wiring line and the capacitance wiring line, the connection wiring line being formed on an interlayer insulating film that covers a gate electrode of the thin film transistor, the capacitance wiring line being formed on the same interlayer insulating film on which a pixel electrode of the organic light emitting diode is formed,

wherein the connection wiring line is connected to a source region or a drain region of the thin film transistor.

10. (Previously presented) A light emitting device as claimed in claim 9, wherein the insulating film is formed by anodization.

11. (Previously presented) A light emitting device as claimed in claim 9, wherein the capacitance wiring line and the pixel electrode are formed from the same conductive film.

12. (Original) An electric appliance comprising the light emitting device according to claim 9, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

13. (Currently amended) A light emitting device comprising a thin film transistor, a storage capacitor, **[[storage,]]** and an organic light emitting diode,

wherein the storage capacitor **[[storage]]** has a connection wiring line, a capacitance wiring line, and an insulating film formed between the connection wiring line and the

capacitance wiring line, the connection wiring line being formed on an interlayer insulating film that covers a gate electrode of the thin film transistor, the capacitance wiring line being formed on the same interlayer insulating film on which a pixel electrode of the organic light emitting diode is formed,

wherein the connection wiring line is connected to a source region or a drain region of the thin film transistor,

wherein the luminance of the organic light emitting diode is controlled by an analog video signal.

14. (Previously presented) A light emitting device as claimed in claim 13, wherein the insulating film is formed by anodization.

15. (Previously presented) A light emitting device as claimed in claim 13, wherein the capacitance wiring line and the pixel electrode are formed from the same conductive film.

16. (Original) An electric appliance comprising the light emitting device according to claim 13, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

17. (Currently amended) A light emitting device comprising:
a source line, a power supply line, a switching thin film transistor, a driving thin film transistor formed over a substrate,
an interlayer insulating film over the source line, the power supply line, the switching thin film transistor, and the driving thin film transistor,
a storage capacitor **[[storage]]** over the interlayer insulating film, and
an organic light emitting diode over the interlayer insulating film,

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

wherein the storage capacitor **[[storage]]** has the connection wiring line, a capacitance wiring line, and an insulating film formed between the connection wiring line and the capacitance wiring line.

18. (Previously presented) A light emitting device as claimed in claim 17, wherein the insulating film is formed by anodization.

19. (Previously presented) A light emitting device as claimed in claim 17, wherein the capacitance wiring line and the pixel electrode are formed from the same conductive film.

20. (Original) An electric appliance comprising the light emitting device according to claim 17, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

21. (Currently amended) A light emitting device comprising:

a source line, a power supply line, a switching thin film transistor, a driving thin film transistor, a first storage capacitor, **[[storage,]]** and an organic light emitting diode over a substrate,

a second storage capacitor **[[storage]]** over the first storage capacitor, **[[storage,]]**

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

wherein the first storage capacitor **[[storage]]** has a capacitance electrode, a semiconductor layer, and a first insulating film formed between the capacitance electrode and the semiconductor layer, and

wherein the second storage capacitor **[[storage]]** has the capacitance electrode, the power supply line, and second insulating film formed between the capacitance electrode and the power supply line, the capacitance electrode being formed of the same conductive film as the gate electrode of the driving thin film transistor.

22. (Previously presented) A light emitting device as claimed in claim 21, wherein the insulating film is formed by anodization.

23. (Canceled)

24. (Original) An electric appliance comprising the light emitting device according to claim 21, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

25. (Currently amended) A light emitting device comprising:
a source line, a power supply line, a switching thin film transistor, and a driving thin film transistor over a substrate,

an interlayer insulating film over the source line, the power supply line, the switching thin film transistor, and the driving thin film transistor,

a storage capacitor **[[storage]]** over the interlayer insulating film, and

an organic light emitting diode over the interlayer insulating film,

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

wherein the storage capacitor **[[storage]]** has the connection wiring line, a capacitance wiring line, and an insulating film formed between the connection wiring line and the capacitance wiring line, and

wherein the connection wiring line overlaps an active layer of the switching thin film transistor.

26. (Previously presented) A light emitting device as claimed in claim 25, wherein the insulating film is formed by anodization.

27. (Previously presented) A light emitting device as claimed in claim 25, wherein the capacitance wiring line and the pixel electrode are formed from the same conductive film.

28. (Original) An electric appliance comprising the light emitting device according to claim 25, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

29. (Currently amended) A light emitting device comprising:

a source line, a power supply line, a switching thin film transistor, a driving thin film transistor, a first storage capacitor, **[[storage,]]** and an organic light emitting diode over a substrate,

a second storage capacitor **[[storage]]** over the first storage capacitor, **[[storage,]]**

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

wherein the first storage capacitor **[[storage]]** has a capacitance electrode, a semiconductor layer, and a first insulating film formed between the capacitance electrode and the semiconductor layer,

wherein the second storage capacitor **[[storage]]** has the capacitance electrode, the power supply line, and second insulating film formed between the capacitance electrode and the power supply line, the capacitance electrode being formed of the same conductive film as the gate electrode of the driving thin film transistor, and

wherein the connection wiring line overlaps an active layer of the switching thin film transistor.

30. (Previously presented) A light emitting device as claimed in claim 29, wherein the insulating film is formed by anodization.

31. (Canceled)

32. (Original) An electric appliance comprising the light emitting device according to claim 29, wherein the electronic appliance is selected from the group consisting of an organic

light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

33. (Currently amended) A light emitting device comprising:

a source line, a power supply line, a switching thin film transistor, and a driving thin film transistor over a substrate,

an interlayer insulating film over the source line, the power supply line, the switching thin film transistor, and the driving thin film transistor,

a storage capacitor **[[storage]]** over the interlayer insulating film, and

an organic light emitting diode over the interlayer insulating film,

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

wherein the storage capacitor **[[storage]]** has the connection wiring line, a capacitance wiring line, and an insulating film formed between the connection wiring line and the capacitance wiring line, and

wherein a drain current of the driving thin film transistor is controlled by an analog video signal inputted to the source line and the drain current flows into the organic light emitting diode.

34. (Previously presented) A light emitting device as claimed in claim 33, wherein the insulating film is formed by anodization.

35. (Previously presented) A light emitting device as claimed in claim 33, wherein the capacitance wiring line and the pixel electrode are formed from the same conductive film.

36. (Original) An electric appliance comprising the light emitting device according to claim 33, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

37. (Currently amended) A light emitting device comprising:

a source line, a power supply line, a switching thin film transistor, a driving thin film transistor, a first storage capacitor, **[[storage,]]** and an organic light emitting diode over a substrate,

a second storage capacitor **[[storage]]** over the first storage capacitor, **[[storage,]]**

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

wherein the first storage capacitor **[[storage]]** has a capacitance electrode, a semiconductor layer, and a first insulating film formed between the capacitance electrode and the semiconductor layer,

wherein the second storage capacitor **[[storage]]** has the capacitance electrode, the power supply line, and second insulating film formed between the capacitance electrode and the power supply line, the capacitance electrode being formed of the same conductive film as the gate electrode of the driving thin film transistor, and

wherein a drain current of the driving thin film transistor is controlled by an analog video signal inputted to the source line and the drain current flows into the organic light emitting diode.

38. (Previously presented) A light emitting device as claimed in claim 37, wherein the insulating film is formed by anodization.

39. (Canceled)

40. (Original) An electric appliance comprising the light emitting device according to claim 37, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

41. (Currently amended) A light emitting device comprising:
a source line, a power supply line, a switching thin film transistor, a driving thin film transistor, and a first storage capacitor **[[storage]]** over a substrate,
an interlayer insulating film over the source line, the power supply line, the switching thin film transistor, the driving thin film transistor, and the first capacitor,
a second storage capacitor **[[storage]]** over the interlayer insulating film, and
an organic light emitting diode over the interlayer insulating film,
wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,
wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,
wherein the first storage capacitor **[[storage]]** has a capacitance electrode, a semiconductor layer, and a first insulating film formed between the capacitance electrode and the semiconductor layer, the capacitance electrode being formed of the same conductive film as the gate electrode of the driving thin film transistor, and the semiconductor layer being formed at the

same time active layers of the switching thin film transistor and the driving thin film transistor are formed., and

wherein the second storage capacitor **[[storage]]** has the connection wiring line, a capacitance wiring line, and a second insulating film formed between the connection wiring line and the capacitance wiring line.

42. (Previously presented) A light emitting device as claimed in claim 41, wherein the insulating film is formed by anodization.

43. (Previously presented) A light emitting device as claimed in claim 41, wherein the capacitance wiring line and the pixel electrode are formed from the same conductive film.

44. (Original) An electric appliance comprising the light emitting device according to claim 41, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

45. (Currently amended) A light emitting device having a source line, a power supply line, a switching thin film transistor, a driving thin film transistor, a first storage capacitor, **[[storage,]]** a second storage capacitor, **[[storage,]]** and an organic light emitting diode,

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

wherein the connection wiring line is formed on an interlayer insulating film that covers a gate electrode of the switching thin film transistor,

wherein the first storage capacitor **[[storage]]** has the connection wiring line, a capacitance wiring line, and an insulating film formed between the connection wiring line and the capacitance wiring line,

wherein the second storage capacitor **[[storage]]** has a capacitance electrode, the power supply line, and the interlayer insulating film formed between the capacitance electrode and the power supply line, the capacitance electrode being formed of the same conductive film as the gate electrode of the driving thin film transistor.

46. (Previously presented) A light emitting device as claimed in claim 45, wherein the insulating film is formed by anodization.

47. (Previously presented) A light emitting device as claimed in claim 45, wherein the capacitance wiring line and the pixel electrode are formed from the same conductive film.

48. (Original) An electric appliance comprising the light emitting device according to claim 45, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

49. (Currently amended) A light emitting device comprising:
a source line, a power supply line, a switching thin film transistor, a driving thin film transistor, and a first storage capacitor **[[storage]]** over a substrate,
an interlayer insulating film over the source line, the power supply line, the switching transistor, the driving thin film transistor, and the first storage capacitor, **[[storage,]]**
a second storage capacitor **[[storage]]** over the interlayer insulating film, and

an organic light emitting diode over the interlayer insulating film,
wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

wherein the first storage capacitor **[[storage]]** has a capacitance electrode, a semiconductor layer, and a first insulating film formed between the capacitance electrode and the semiconductor layer, the capacitance electrode being formed of the same conductive film as the gate electrode of the driving thin film transistor, the semiconductor layer being formed at the same time active layers of the switching thin film transistor and the driving thin film transistor are formed,

wherein the second storage capacitor **[[storage]]** has the connection wiring line, a capacitance wiring line, and a second insulating film formed between the connection wiring line and the capacitance wiring line, and

wherein the connection wiring line overlaps the active layer of the switching thin film transistor.

50. (Previously presented) A light emitting device as claimed in claim 49, wherein the insulating film is formed by anodization.

51. (Previously presented) A light emitting device as claimed in claim 49, wherein the capacitance wiring line and the pixel electrode are formed from the same conductive film.

52. (Original) An electric appliance comprising the light emitting device according to claim 49, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile

computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

53. (Currently amended) A light emitting device having a source line, a power supply line, a switching thin film transistor, a driving thin film transistor, a first storage capacitor, **[[storage,]]** a second storage capacitor, **[[storage,]]** and an organic light emitting diode,

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

wherein the connection wiring line is formed on an interlayer insulating film that covers a gate electrode of the switching thin film transistor,

wherein the first storage capacitor **[[storage]]** has the connection wiring line, a capacitance wiring line, and an insulating film formed between the connection wiring line and the capacitance wiring line,

wherein the second storage capacitor **[[storage]]** has a capacitance electrode, the power supply line, and the interlayer insulating film formed between the capacitance electrode and the power supply line, the capacitance electrode being formed of the same conductive film as the gate electrode of the driving thin film transistor,

wherein the connection wiring line overlaps the active layer of the switching thin film transistor.

54. (Previously presented) A light emitting device as claimed in claim 53, wherein the insulating film is formed by anodization.

55. (Previously presented) A light emitting device as claimed in claim 53, wherein the capacitance wiring line and the pixel electrode are formed from the same conductive film.

56. (Original) An electric appliance comprising the light emitting device according to claim 53, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

57. (Currently amended) A light emitting device having a source line, a power supply line, a switching thin film transistor, a driving thin film transistor, a first storage capacitor, **[[storage,]]** a second storage capacitor, **[[storage,]]** a third storage capacitor, **[[storage,]]** and an organic light emitting diode,

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

wherein the connection wiring line is formed on an interlayer insulating film that covers a gate electrode of the switching thin film transistor,

wherein the first storage capacitor **[[storage]]** has the connection wiring line, a capacitance wiring line, and a first insulating film formed between the connection wiring line and the capacitance wiring line,

wherein the second storage capacitor **[[storage]]** has a capacitance electrode, a semiconductor layer, and a second insulating film formed between the capacitance electrode and the semiconductor layer, the capacitance electrode being formed of the same conductive film as the gate electrode of the driving thin film transistor, the semiconductor layer being formed at the

same time active layers of the switching thin film transistor and the driving thin film transistor are formed,

wherein the third storage capacitor **[[storage]]** has the capacitance electrode, the power supply line, and the interlayer insulating film formed between the capacitance electrode and the power supply line.

58. (Previously presented) A light emitting device as claimed in claim 57, wherein the insulating film is formed by anodization.

59. (Previously presented) A light emitting device as claimed in claim 57, wherein the capacitance wiring line and the pixel electrode are formed from the same conductive film.

60. (Original) An electric appliance comprising the light emitting device according to claim 57, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

61. (Currently amended) A light emitting device having a source line, a power supply line, a switching thin film transistor, a driving thin film transistor, a first storage capacitor, **[[storage,]]** a second storage capacitor, **[[storage,]]** a third storage capacitor, **[[storage,]]** and an organic light emitting diode,

wherein the switching thin film transistor has a source region and a drain region one of which is connected to the source line and the other of which is connected to a gate electrode of the driving thin film transistor through a connection wiring line,

wherein the driving thin film transistor has a source region and a drain region one of which is connected to the power supply line and the other of which is connected to a pixel electrode of the organic light emitting diode,

wherein the connection wiring line is formed on an interlayer insulating film that covers a gate electrode of the switching thin film transistor,

wherein the first storage capacitor **[[storage]]** has the connection wiring line, a capacitance wiring line, and a first insulating film formed between the connection wiring line and the capacitance wiring line,

wherein the second storage capacitor **[[storage]]** has a capacitance electrode, a semiconductor layer, and a second insulating film formed between the capacitance electrode and the semiconductor layer, the capacitance electrode being formed of the same conductive film as the gate electrode of the driving thin film transistor, the semiconductor layer being formed at the same time active layers of the switching thin film transistor and the driving thin film transistor are formed,

wherein the third storage capacitor **[[storage]]** has the capacitance electrode, the power supply line, and the interlayer insulating film formed between the capacitance electrode and the power supply line, and

wherein the connection wiring line overlaps the active layer of the switching thin film transistor.

62. (Previously presented) A light emitting device as claimed in claim 61, wherein the insulating film is formed by anodization.

63. (Previously presented) A light emitting device as claimed in claim 61, wherein the capacitance wiring line and the pixel electrode are formed from the same conductive film.

64. (Original) An electric appliance comprising the light emitting device according to claim 61, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.

65. (Currently amended) A light emitting device comprising:
a plurality of pixels each having a thin film transistor, a pixel electrode, and a storage capacitor, **[[storage,]]**

wherein all of the storage capacitors **[[storages]]** of the plurality of pixels share one capacitance wiring line, the capacitance wiring line formed on a different layer from a gate electrode of the thin film transistor,

wherein each of the storage capacitors **[[storages]]** of the plurality of pixels has a connection wiring line, the capacitance wiring line, and an insulating film being formed between the connection wiring line and the one capacitance wiring line,

wherein the connection wiring line is connected to a source region or a drain region of the thin film transistor, and

wherein the capacitance wiring line is formed on a same interlayer insulating film on which a pixel electrode is formed,

wherein the one capacitance wiring line overlaps an active layer of the thin film transistor of each of the plurality of pixels.

66. (Previously presented) A light emitting device as claimed in claim 65, wherein the insulating film is formed by anodization.

67. (Previously presented) A light emitting device as claimed in claim 65, wherein the capacitance wiring line and a pixel electrode are formed from the same conductive film.

68. (Original) An electric appliance comprising the light emitting device according to claim 65, wherein the electronic appliance is selected from the group consisting of an organic light emitting diode display, a digital still camera, a notebook personal computer, a mobile computer, a portable image reproducing device, a goggle type display, a video camera, and a cellular phone.